

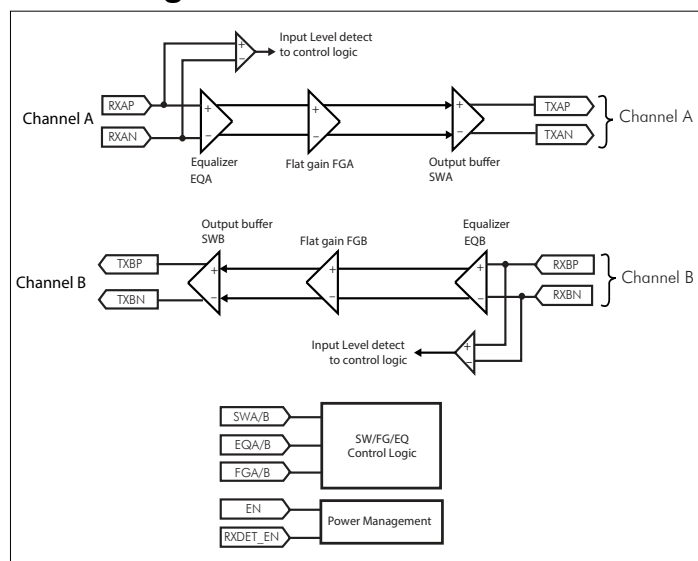
**PI3EQX1002E**

**1-Port USB3.2 Gen2 ReDriver**

## Features

- 10Gbps Serial Link with Linear Equalizer
- USB 3.2 Gen 2 and USB 3.2 Gen 1 Compatible
- Full Compliancy to USB 3.2 Super Speed Standard
- Two 10Gbps Differential Signal Pairs
- Pin Adjustable Receiver Equalization
- Pin Adjustable Output Linear Swing
- Pin Adjustable Flat Gain
- 100Ω Differential CML I/Os
- Automatic Receiver Detect
- Auto "Slumber" Mode for Adaptive Power Management
- Single Supply Voltage: 3.3V
- Patented Technology
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please [contact us](https://www.diodes.com/quality/lead-free/) or your local Diodes representative.  
<https://www.diodes.com/quality/lead-free/>
- Packaging:
  - ◆ 24-pin, TQFN 2.5mm × 2.5 mm (ZR24)

## Block Diagram



### Notes:

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
2. See <https://www.diodes.com/quality/lead-free/> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

*ReDriver is a trademark of Diodes Incorporated.*

PI3EQX1002E

Document Number DS41499 Rev 6-2

## Description

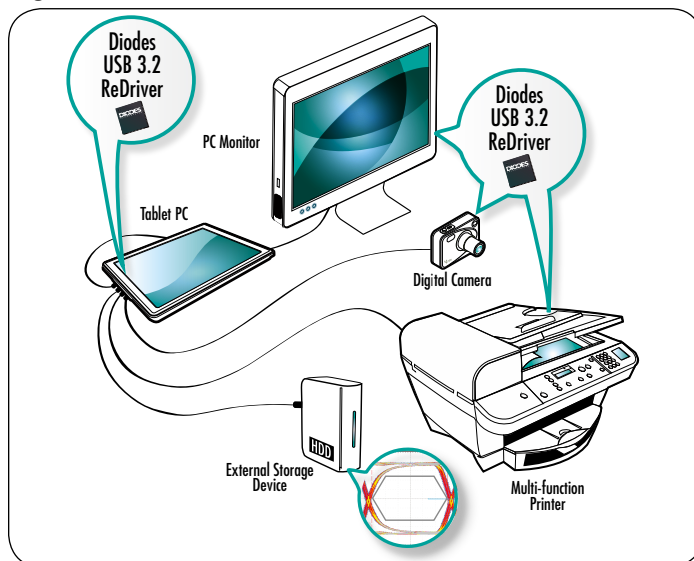
The PI3EQX1002E is a low-power, high-performance, 10.0Gbps, 1-Port USB 3.2 linear ReDriver™ designed specifically for the USB 3.2 protocol.

The device provides programmable equalization, swing, and flat gain to optimize performance over a variety of physical mediums by reducing intersymbol interference. PI3EQX1002E supports two 100Ω differential CML data I/Os between the Protocol ASIC to a switch fabric, over cable, or to extend the signals across other distant data pathways on the user's platform.

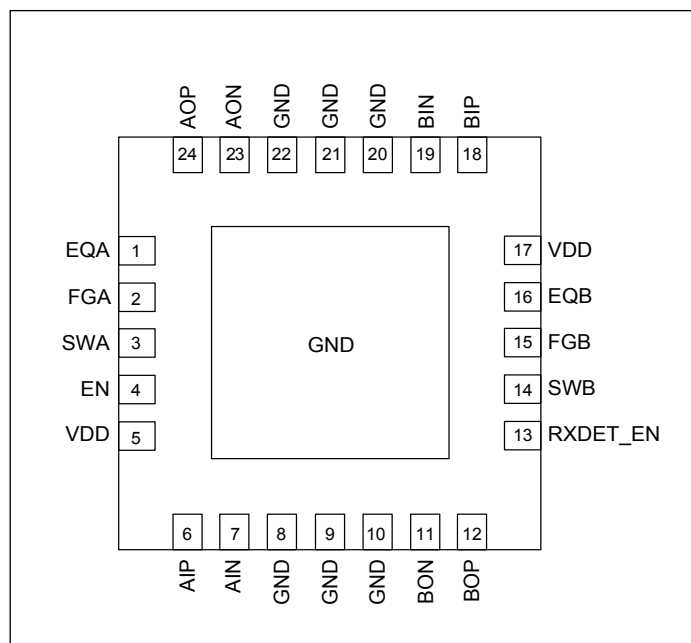
The integrated equalization circuitry provides flexibility with signal integrity of the signal before the ReDriver. Each channel operates fully independently. The channels' input signal level determines whether the output is active.

The PI3EQX1002E also includes an automatic receiver detect function. The receiver detection loop is active again if the corresponding channel's signal detector is idle for longer than 7.3ms. The channel moves to unplug mode if load is not detected, or it returns to low-power mode (slumber mode) due to inactivity.

**Figure 1**



## Pin Configuration



## Pin Description

Pin #	Pin Name	Type	Description
5, 17	VDD	Power	3.3V power supply, $\pm 0.3V$
2 15	FGA FGB	Input	The DC flat gain selection. 4-level input pins. With internal 100k $\Omega$ pullup resistor and 200k $\Omega$ pulldown resistor.
3 14	SWA SWB	Input	The Output Swing selection. 4-level input pins. With internal 100k $\Omega$ pullup resistor and 200k $\Omega$ pulldown resistor.
1 16	EQA EQB	Input	The EQ selection. 4-level input pins. With internal 100k $\Omega$ pullup resistor and 200k $\Omega$ pulldown resistor.
6, 7 18, 19	AIP, AIN BIP, BIN	Input	CML input terminals. With selectable input termination between 50 $\Omega$ to VDD, 67k $\Omega$ to VbiasRx, or 67k $\Omega$ to GND.
24, 23 12, 11	AOP, AON BOP, BON	Output	CML output terminals. With selectable output termination between 50 $\Omega$ to VDD, 6k $\Omega$ to VDD, 6k $\Omega$ to VbiasTx, or Hi-Z.
13	RXDET_EN	Input	Receiver detection Enable pin. With internal 300k $\Omega$ pullup resistor. “High” – Receiver detection is enabled. “Low” – Receiver detection is disabled.
4	EN	Input	Channel Enable. With internal 300k $\Omega$ pullup resistor. “High” – Channel is in normal operation. “Low” – Channel is in power down mode.
8, 9, 10, 20, 21, 22, Center Pad	GND	GND	Supply Ground

## Power Management

Notebooks, netbooks, and other power-sensitive consumer devices require judicious use of power in order to maximize battery life. In order to minimize the power consumption of our devices, Diodes added an additional adaptive power-management feature. When a signal detector is idle for longer than 1.3ms, the corresponding channel moves to low-power mode ONLY, which means both channels will move to low-power mode individually.

In low-power mode, the signal detector still monitors the input channel. If a channel is in low-power mode and the input signal is detected, the corresponding channel wakes up immediately. If a channel is in low-power mode and the signal detector is idle longer than 6ms, the receiver detection loop is active again. If load is not detected, then the channel moves to device unplug mode and monitors the load continuously. If load is detected, it returns to low-power mode, and receiver detection is active again per 6ms.

## Operating Modes

Mode	$R_{IN}$	$R_{OUT}$
PD	67k $\Omega$ to GND	HIZ
Unplug Mode	67k $\Omega$ to VbiasRx	6k $\Omega$ to VbiasTx
Deep Slumber Mode	50 $\Omega$ to Vdd	6k $\Omega$ to VbiasTx
Slumber Mode	50 $\Omega$ to Vdd	6k $\Omega$ to Vdd
Active Mode	50 $\Omega$ to Vdd	50 $\Omega$ to Vdd

### Equalization Setting:

EQA/B are the selection pins for the equalization selection.

	Equalizer Setting (dB)	
<i>EQA/B</i>	@2.5GHz	@5GHz
0 (Tie 1kΩ to GND)	6.7	12.4
R (Tie 68kΩ to GND)	3.5	8.0
F (Leave Open)	5.3	10.6
1 (Tie 1kΩ to VDD)	8.4	14.6

### Flat Gain Setting:

FGA/B are the selection pins for the DC gain.

	Flat Gain Settings
<i>FGA/B</i>	<i>dB</i>
0 (Tie 1kΩ to GND)	-1.6
R (Tie 68kΩ to GND)	-0.5
F (Leave Open)	1.0
1 (Tie 1kΩ to VDD)	2.7

### -1dB Compression Point Linear Swing Setting:

SWA/B are the selection pins for the output linear swing setting.

	Output Linear Swing Settings
<i>SWA/B</i>	<i>mVppd</i>
0 (Tie 1kΩ to GND)	800
R (Tie 68KΩ to GND)	1200
F (Leave Open)	1000 (Default)
1 (Tie 1kΩ to VDD)	1100

### Channel Enable Setting:

EN is the channel enable pin.

	Channel Enable Setting
<i>EN</i>	<i>Setting</i>
0	Disabled
1	Enabled (Default)

### Receiver Detection Setting:

RXDET\_EN is the receiver detection pin.

	Receiver Detection Setting
<i>RXDET_EN</i>	<i>Setting</i>
0	Disabled
1	Enabled (Default)

## Maximum Ratings

(Above which useful life may be impaired. For user guidelines, not tested.)

**Note:**

Storage Temperature.....	–65°C to +150°C
Supply Voltage to Ground Potential .....	–0.5V to +3.8V
DC SIG Voltage.....	–0.5V to V <sub>DD</sub> +0.5V
Output Current .....	–25mA to +25mA
ESD, Human Body Model .....	–7V to +7V
Power Dissipation Continuous .....	1.0W

Stresses greater than those listed under MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

## Control Pin Specifications (V<sub>DD</sub> = 3.3 ± 0.3V TA = 0 to 70°C)

Symbol	Parameter	Min.	Typ.	Max.	Units
<b>2-Level Control Pins</b>					
V <sub>IH</sub>	DC Input Logic High	V <sub>DD</sub> *0.65	—	—	V
V <sub>IL</sub>	DC Input Logic Low	—	—	V <sub>DD</sub> *0.35	V
I <sub>IH</sub>	Input High Current	—	—	25	μA
I <sub>IL</sub>	Input Low Current	-25	—	—	μA
<b>4-Level Control Pins</b>					
V <sub>IH</sub>	DC Input Logic "High"	0.92*V <sub>DD</sub>	V <sub>DD</sub>	—	V
V <sub>IF</sub>	DC Input Logic "Float"	0.59*V <sub>DD</sub>	0.67*V <sub>DD</sub>	0.75*V <sub>DD</sub>	V
V <sub>IR</sub>	DC Input Logic "With Rext to GND"	0.25*V <sub>DD</sub>	0.33*V <sub>DD</sub>	0.41*V <sub>DD</sub>	V
V <sub>IL</sub>	DC Input Logic "Low"	—	GND	0.08*V <sub>DD</sub>	V
I <sub>IH</sub>	Input High Current	—	—	50	μA
I <sub>IL</sub>	Input Low Current	-50	—	—	μA
Rext	External Resistor Connects to GND (±5%)	64.6	68	71.4	kΩ

## AC/DC Electrical Characteristics (V<sub>DD</sub> = 3.3 ± 0.3V TA = 0 to 70°C)

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Units
<b>Power and Latency</b>						
V <sub>dd-3.3</sub>	Supply Voltage	—	3.0	3.3	3.6	V
I <sub>active</sub>	Active Mode Current Consumption	EN=1 (V <sub>DD</sub> =3.3V, 10Gbps, compliance test pattern, SWx=F, RXDET_EN=High)	—	130	167	mA
I <sub>slumber</sub>	Slumber Mode Current Consumption	EN=1 (V <sub>DD</sub> =3.3V, no input signal longer than T <sub>slumber</sub> , RXDET_EN=High)	—	16	19	mA
I <sub>DeepSlumber</sub>	Deep Slumber Mode Current Consumption	EN=1 (V <sub>DD</sub> =3.3V, no input signal longer than T <sub>DeepSlumber</sub> , RXDET_EN=High)	—	0.4	0.6	
I <sub>unplug</sub>	Unplug Mode Current Consumption	EN=1, no output load is detected, RXDET_EN=High	—	0.3	0.45	
I <sub>pd</sub>	Power Down Mode Current Consumption	EN=0	—	10	50	μA

## AC/DC Electrical Characteristics Cont.

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Units
$t_{pd}$	Latency	From input to output	—	—	2	ns
<b>CML Receiver Input (100Ω Differential)</b>						
Receiver Electrical Specification						
$C_{rxparasitic}$	The Parasitic Capacitor for RX	—	—	—	1.0	pF
$R_{RX-DIFF-DC}$	DC Differential Input Impedance	—	72	—	120	Ω
$R_{RX-SINGLE\_DC}$	DC Single Ended Input Impedance	DC impedance limits are need to guarantee RxDet. Measured with respect to GND over a voltage of 500mV max	18	—	30	
$Z_{RX-HIZ-DC-PD}$	DC Input CM Input Impedance for $V > 0$ During Reset or Power Down	( $V_{cm}=0$ to 500mV)	25	—	—	kΩ
$C_{ac\_coupling}$	AC Coupling Capacitance	—	75	—	265	nF
$V_{RX-CM-AC-P}$	Common Mode Peak Voltage	AC up to 5GHz	—	—	150	mVpeak
$V_{RX-CM-DC-Ac-Active-Idle-Delta-P}$	Common Mode Peak Voltage $ Avg_{uo}( V_{TX-D+} + V_{TX-D-} )/2 - Avg_{u1}( V_{TX-D+} + V_{TX-D-} )/2 $	Between U0 and U1. AC up to 5GHz	—	—	200	mVpeak
<b>Transmitter Electrical Specification</b>						
$V_{TX-DIFF-PP}$	Output Differential p-p Voltage Swing	Differential Swing $ V_{TX-D+} - V_{TX-D-} $	—	—	1.2	Vppd
$R_{TX-DIFF-DC}$	DC Differential TX Impedance	—	72	—	120	Ω
$V_{TX-RCV-DET}$	The Amount of Voltage Change Allowed During RxDet	—	—	—	600	mV
$C_{ac\_coupling}$	AC Coupling Capacitance	—	75	—	265	nF
$T_{TX-EYE}(10Gbps)$	Transmitter eye, Include all Jitter	At the silicon pad. 10Gbps	0.646	—	—	UI
$T_{TX-EYE}(5Gbps)$	Transmitter eye, Include all Jitter	At the silicon pad. 5Gbps	0.625	—	—	UI
$T_{TX-DJ-DD}(10Gbps)$	Transmitter Deterministic Jitter	At the silicon pad. 10Gbps	—	—	0.17	UI
$T_{TX-DJ-DD}(5Gbps)$	Transmitter Deterministic Jitter	At the silicon pad. 5Gbps	—	—	0.205	UI
$C_{txparasitic}$	The Parasitic Capacitor for TX	—	—	—	1.1	pF
$R_{TX-DC-CM}$	Common Mode DC Output Impedance	—	18	—	30	Ω
$V_{TX-DC-CM}$	The instantaneous allowed DC common mode voltage at the connector side of the AC coupling capacitors	$ V_{TX-D+} + V_{TX-D-} /2$	0	—	2.2	V
$V_{TX-C}$	Common Mode Voltage	$ V_{TX-D+} + V_{TX-D-} /2$	VDD-2V	—	VDD	V
$V_{TX-CM-AC-PP-Active}$	Active Mode TX AC Common Mode Voltage	$V_{TX-D+} + V_{TX-D-}$ for both time and amplitude	—	—	100	mVpp

**AC/DC Electrical Characteristics Cont.**

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Units
$V_{TX-CM-DC-Active\_Idle-Delta}$	Common mode delta voltage $ Avg_{uo}( V_{TX-D+} + V_{TX-D-} )/2 - Avg_{u1}( V_{TX-D+} + V_{TX-D-} )/2 $	Between U0 to U1	—	—	200	mV-peak
$V_{TX-Idle-Diff-AC-pp}$	Idle Mode AC Common Mode Delta Voltage $ V_{TX-D+} - V_{TX-D-} $	Between Tx+ and Tx- in idle mode. Use the HPF to remove DC components. =1/LPF. No AC and DC signals are applied to Rx terminals.	—	—	10	mVppd
$V_{TX-Idle-Diff-DC}$	Idle Mode DC Common Mode Delta Voltage $ V_{TX-D+} - V_{TX-D-} $	Between Tx+ and Tx- in idle mode. Use the LPF to remove DC components. =1/HPF. No AC and DC signals are applied to Rx terminals.	—	—	10	mV
<b>Channel Performance</b>						
$G_p$	Peaking Gain (Compensation at 5GHz, relative to 100MHz, 100mV <sub>p-p</sub> sine wave input)	EQx=0 EQx=R EQx=F EQx=1	—	12.4 8 10.6 14.6	—	dB
		Variation around typical	-3	—	+3	dB
$G_F$	Flat Gain (100MHz, EQx=F, SWx=F)	FQx=0 FQx=R FQx=F FQx=1	—	-1.6 -0.5 1 2.7	—	dB
		Variation around typical	-3	—	+3	dB
$V_{SW\_100M}$	-1dB Compression Point Output Swing (at 100MHz)	SWx=0 SWx=R SWx=F SWx=1	—	800 1200 1000 1100	—	mVppd
$V_{SW\_5G}$	-1dB Compression Point Output Swing (at 5GHz)	SWx=0 SWx=R SWx=F SWx=1	—	750 950 850 900	—	mVppd
DDNEXT	Differential Near-End Crosstalk <sup>(1)</sup>	100MHz to 5GHz, RXDET_EN=1, Figure2	—	-40	—	dB
$V_{noise-input}$	Input-Referred Noise	100MHz to 5GHz, FGx=1, EQx=R, SW=F, Figure 3	—	0.6	—	mV <sub>RMS</sub>
		100MHz to 5GHz, FGx=1, EQx=1, SW=F, Figure 3	—	0.5	—	

### AC/DC Electrical Characteristics Cont.

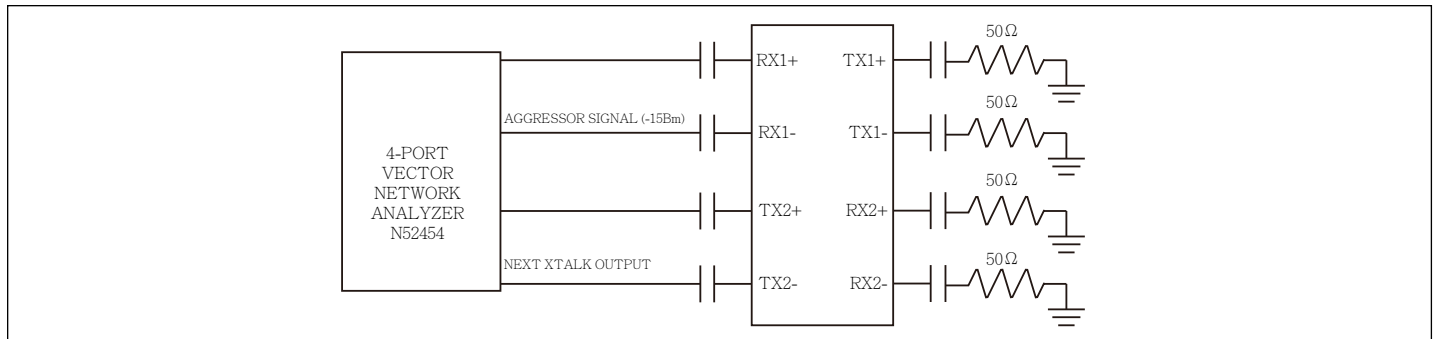
Symbol	Parameter	Conditions	Min.	Typ.	Max.	Units
$V_{\text{noise-output}}$	Output-Referred Noise <sup>(2)</sup>	100MHz to 5GHz, FGx=1, EQx=R, SW=F, Figure 3	—	0.8	—	mV <sub>RMS</sub>
		100MHz to 5GHz, FGx=1, EQx=1, SW=F, Figure 3	—	1	—	

### Signal and Frequency Detectors

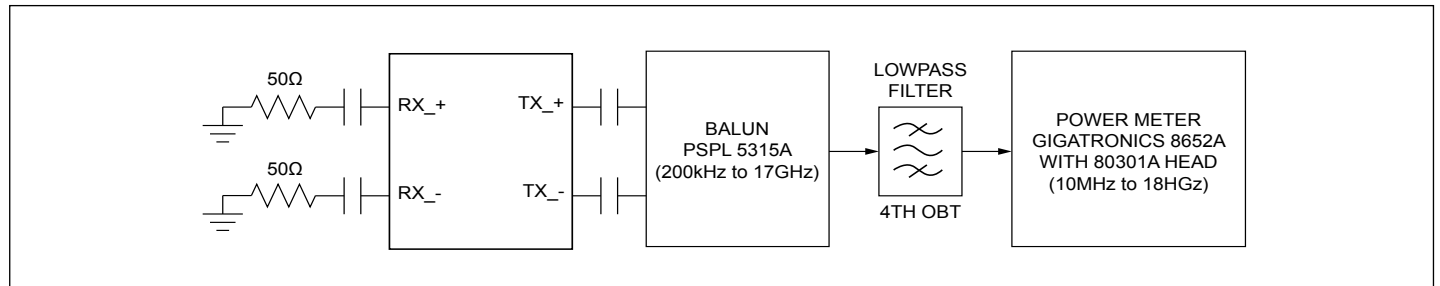
$V_{\text{th\_upm}}$	Unplug Mode Detector Threshold	Threshold of LFPS when the input impedance of the redriver is 67kohm to VbiasRx only. Used in the unplug mode.	200		800	mVppd
$V_{\text{th\_dsm}}$	Deep Slumber Mode Detector Threshold	LFPS signal threshold in Deep slumber mode	100		600	mVppd
$V_{\text{th\_am}}$	Active Mode Detector Threshold	Signal threshold in Active and slumber mode	45		175	mVppd
$F_{\text{th}}$	LFPS Frequency Detector	Detect the frequency of the input CLK pattern	100		400	MHz

**Note:**

1. Measured using a vector-network analyzer (VNA) with -15dbm power level applied to the adjacent input. The VNA detects the signal at the output of the victim channel. All other inputs and outputs are terminated with 50Ω.
2. Guaranteed by design and characterization.

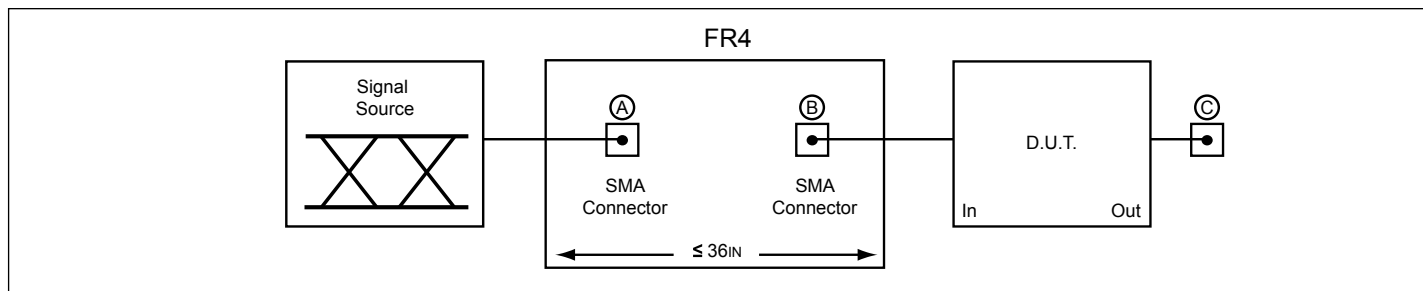


**Figure 2. Channel-Isolation Test Configuration**



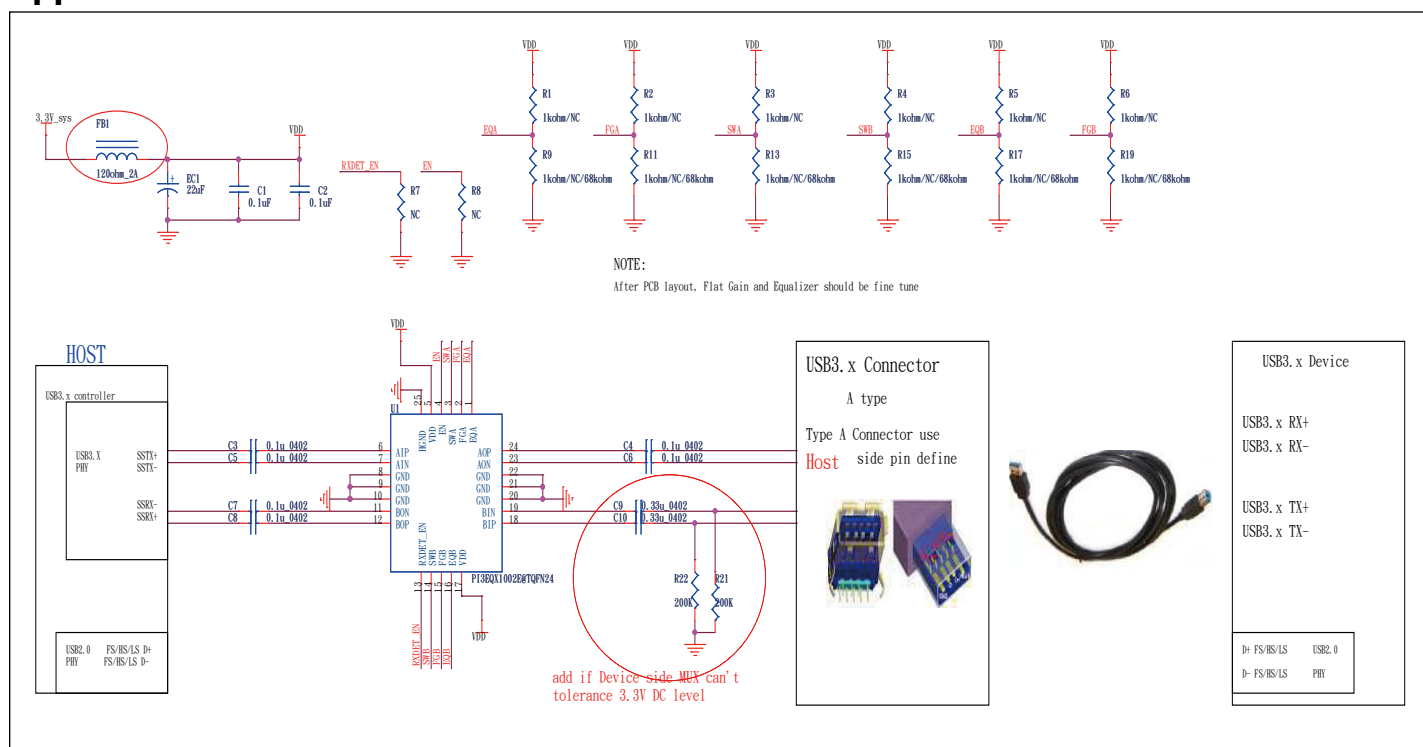
**Figure 3. Noise Test Configuration**





**Figure 4. Test Condition Referenced in the Electrical Characteristic Table**

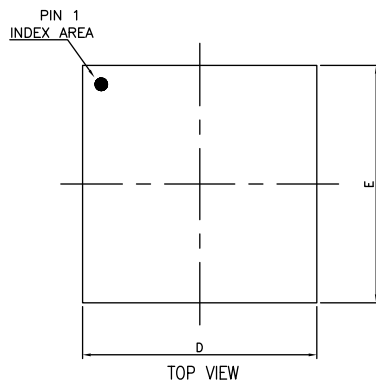
## Application Schematics



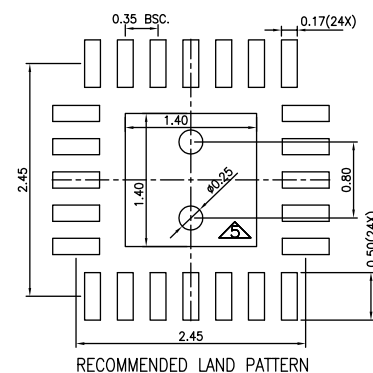
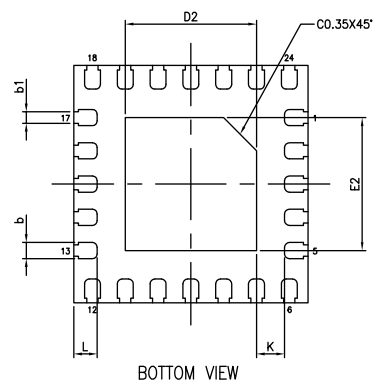
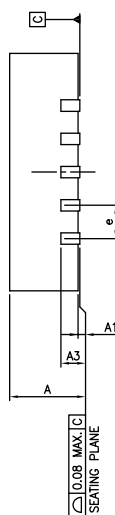
## Part Marking



Y: Year  
W: Workweek  
1st X: Assembly Code  
2nd X: Fab Code  
Bar above fab code means Cu wire

**PI3EQX1002E**
**Packaging Mechanical: 24-TQFN (ZR)**


SYMBOLS	MIN.	NOM.	MAX.
A	0.70	0.75	0.80
A1	0.00	0.02	0.05
A3	0.203 REF.		
b	0.12	0.17	0.22
b1	0.07	0.12	0.17
D	2.45	2.50	2.55
E	2.45	2.50	2.55
e	0.35 BSC		
L	0.20	0.25	0.30
K	0.20	—	—
D2	1.35	1.40	1.45
E2	1.35	1.40	1.45


**NOTE :**

1. ALL DIMENSIONS ARE IN mm. ANGLES IN DEGREES.
2. COPLANARITY APPLIES TO THE EXPOSED THERMAL PAD AS WELL AS THE TERMINALS.
3. REFER JEDEC MO-220
4. RECOMMENDED LAND PATTERN IS FOR REFERENCE ONLY.
5. THERMAL PAD SOLDERING AREA

DATE: 06/18/19

**DESCRIPTION: 24-Contact, Very Very Thin Quad Flat No-Lead (TQFN)**
**PACKAGE CODE: ZR (ZR24)**
**DOCUMENT CONTROL #: PD-2237**
**REVISION: A**
**For latest package info.**

 please check: <http://www.diodes.com/design/support/packaging/pericom-packaging/packaging-mechanicals-and-thermal-characteristics/>
**Ordering Information**

Ordering Number	Package Code	Package Description
PI3EQX1002EZREX	ZR	24-Contact, Very Very Thin Quad Flat No-Lead (TQFN)

**Notes:**

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
2. See <https://www.diodes.com/quality/lead-free/> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
4. E = Pb-free and Green
5. X suffix = Tape/Reel

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  2. support or sustain life and whose failure to perform when properly used in accordance with instructions for use provided in the labeling can be reasonably expected to result in significant injury to the user.
- B. A critical component is any component in a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or to affect its safety or effectiveness.

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